

Excellent Integrated System Limited

Stocking Distributor

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Vishay Semiconductor/Diodes Division SB2D-M3/5BT

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of SB2D-M3/5BT - DIODE RECT 2A 200V DO-214AA

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SB2D thru SB2M

HALOGEN

FREE

Vishay General Semiconductor

Surface Mount Glass Passivated Rectifier



DO-214AA (SMB)

PRIMARY CHARACTERISTICS						
I _{F(AV)}	2.0 A					
V _{RRM}	200 V to 1000 V					
I _{FSM}	55 A					
I _R	1.0 μΑ					
V_F at $I_F = 2.0$ A	0.86 V					
T _J max.	150 °C					
Package	DO-214AA (SMB)					
Diode variations	Single die					

FEATURES

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Low forward voltage drop
- Low leakage current
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes for consumer and telecommunication.

MECHANICAL DATA

Case: DO-214AA (SMB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test **Polarity:** Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	SB2D	SB2G	SB2J	SB2K	SB2M	UNIT
Device marking code		B2D	B2G	B2J	B2K	B2M	
Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	800	1000	٧
Maximum DC forward current (fig. 1)	I _F ⁽¹⁾	2.0			Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	55			Α		
Operating and storage temperature range	T _J , T _{STG}	-55 to +150				°C	

Note

(1) Mounted on 8 mm x 8 mm pad areas, 1 oz. FR4 PCB

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage	I _F = 1.0 A	T _A = 25 °C	V _F ⁽¹⁾	0.90	-	V	
	I _F = 2.0 A	14 - 23 0		0.96	1.15		
	I _F = 1.0 A	T _A = 125 °C		0.78	-		
	I _F = 2.0 A	1A = 125 C		0.86	1.05		
Reverse current	Rated V _B	T _A = 25 °C	I _R ⁽²⁾	0.15	1.0	μΑ	
	nateu v _R	T _A = 125 °C		36	125		
Typical reverse recovery time	$I_F = 0.5 A, I_R = 1$ $I_{rr} = 0.25 A$	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		2.0		μs	
Typical junction capacitance	Rated V _R = 4.0	Rated V _R = 4.0 V, 1 MHz		16		pF	

Notes

 $^{^{(2)}}$ Pulse test: Pulse width, \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	MBOL SB2D SB2G SB2J SB2K SB2M UNIT					UNIT
Typical thermal resistance	R _{0JA} (1)	70					°C/W
Typical thermal resistance	R _{θJM} ⁽¹⁾	10					C/VV

Note

Units mounted on PCB with 8.0 mm x 8.0 mm copper pad areas, 1 oz. FR4 PCB; $R_{\theta JA}$ - junction to ambient $R_{\theta JM}$ - junction to mount

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
SB2J-M3/52T	0.096	52T	750	7" diameter plastic tape and reel				
SB2J-M3/5BT	0.096	5BT	3200	13" diameter plastic tape and reel				

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

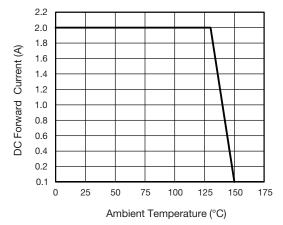


Fig. 1 - Maximum Forward Current Derating Curve

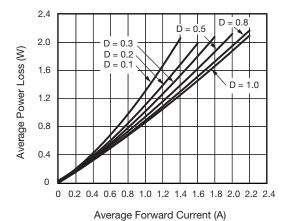


Fig. 2 - Forward Power Loss Characteristics

 $^{^{(1)}}$ Pulse test: 300 μ s pulse width, 1 % duty cycle

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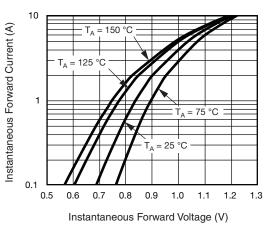


Fig. 3 - Typical Instantaneous Forward Characteristics

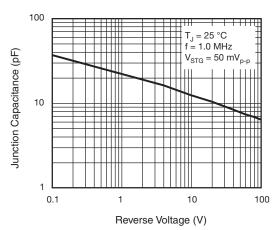


Fig. 5 - Typical Junction Capacitance

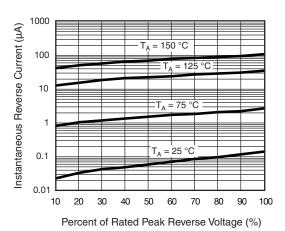


Fig. 4 - Typical Reverse Characteristics

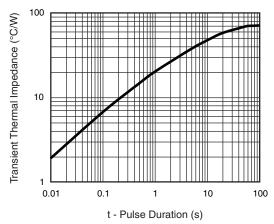
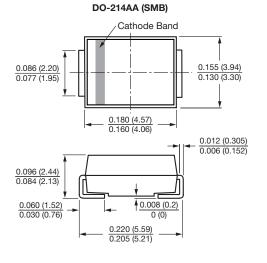
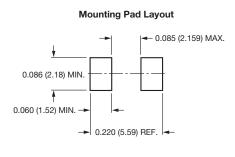


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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